

View Online at <https://aerobasegroup.com/nsn/5962-01-122-4539>

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Temperature Range:

-0.0/+75.0 degrees celsius

Storage Temperature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and 3-state output and programmable and programmed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.5 volts power source and 5.5 volts power source

Time Rating Per Characteristic:

70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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